ELSEVIER

Solar Energy Materials and Solar Cells 34 (1994) 581–589

Solar Energy Materials and Solar Cells

Author Index Volume 34

Aberle, A.G., G. Heiser and M.A. Green, Two-dimensional minority carrier flow in high-efficiency silicon solar cells at short-circuit, open-circuit and maximum power point operating conditions 34 (1994) 149
Adachi, K., see Ikeda, T. 34 (1994) 379
Adachi, T., see Ohira, T. 34 (1994) 565
Adanu, K.G., Promoting photovoltaic electricity usage in developing countries — Experience from Ghana 34 (1994) 67
Amesz, P.H., see Leguijt, C. 34 (1994) 177
Aratani, F., see Yuge, N. 34 (1994) 243
Arimoto, S., H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani, High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure 34 (1994) 257
Asano, A., see Sichanugrist, P. 34 (1994) 415
Asaoka „ K., M. Izumina, Y. Tawada, T. Hama, M. Itoh, Y. Suzuki, M. Ohnishi and R. Shimokawa, Current-induced degradation method for stabilization of a-Si solar cell 34 (1994) 465
Ashida, Y., Single-junction a-Si solar cells with over 13% efficiency 34 (1994) 291
Ashida, Y., see Tanaka, H. 34 (1994) 493
Azuma, M., see Yokoi, T. 34 (1994) 517

Baba, H., see Yuge, N. 34 (1994) 243
Baba, T., see Matsuyama, T. 34 (1994) 285
Banerjee, A., see Guha, S. 34 (1994) 329
Basore, P.A., J.M. Gee, M.E. Buck, W.K. Schubert and D.S. Ruby, Simplified high-efficiency silicon cell processing 34 (1994) 91
Bauser, E., see Konuma, M. 34 (1994) 251
Bubenzer, A., P. Lechner, H. Schade and H. Rübel, Process technology for mass production of large-area a-Si solar modules 34 (1994) 347
Buck, M.E., see Basore, P.A. 34 (1994) 91

Chen, Z., see Rohatgi, A. 34 (1994) 227
Chen, Z.H., see Leguijt, C. 34 (1994) 177
Chida, A., see Nomoto, K. 34 (1994) 339
Crotty, J., see Rohatgi, A. 34 (1994) 227
Czech, E., see Konuma, M. 34 (1994) 251

Daey Ouwens, J., see Schropp, R.E.I. 34 (1994) 455
De, A., see Wenas, W.W. 34 (1994) 313
de Gooijer, H., see Schropp, R.E.I. 34 (1994) 455
Deguchi, M., see Arimoto, S. 34 (1994) 257

Deki, H., M. Ohmura, S. Miyazaki and M. Hirose, Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells 34 (1994) 431
Diao, H.W., see Li, L.Q. 34 (1994) 571

Ebong, A., see Honsberg, C.B. 34 (1994) 117
Egashira, N., see Yoshida, A. 34 (1994) 211
Eikelboom, J.A., see Leguijt, C. 34 (1994) 177
Elgamel, H.E., M.Y. Ghannam, C. Vinckier, J. Nijs, R. Mertens and R. Van Overstraeten, Boosting the efficiency of solar cells fabricated on electromagnetic cold crucible cast multicrystalline silicon by means of hydrogen passivation 34 (1994) 237
Endoh, K., see Yoshioka, K. 34 (1994) 125

Fath, P., see Keppner, H. 34 (1994) 201
Flückiger, R., see Keppner, H. 34 (1994) 201
Fortmann, C., see Keppner, H. 34 (1994) 201
Fujii, T., K. Sameshima, H. Okada, K. Yoshida, T. Hashimoto, M. Yoshimoto, T. Fuyuki and H. Matsunami, Characterization of hydrogenated amorphous silicon–carbon films deposited by hybrid-plasma CVD 34 (1994) 409
Fujikake, S., H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai, Light-induced recovery of a-Si solar cells 34 (1994) 449
Fujimoto, K., Y. Sogawa, K. Shima, Y. Okayasu and K. Kumagai, High efficiency silicon solar cells by plasma-CVD method 34 (1994) 193
Fujisawa, K., see Igari, S. 34 (1994) 473
Fukawa, Y., see Fukui, K. 34 (1994) 111
Fukuda, N., see Tanaka, H. 34 (1994) 493
Fukui, K., Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe, Large-area high-efficiency single crystalline silicon solar cells 34 (1994) 111
Furlan, J., see Popović, P. 34 (1994) 393
Furlan, J., see Smole, F. 34 (1994) 385
Fuyuki, T., see Fujii, T. 34 (1994) 409

Gee, J.M., see Basore, P.A. 34 (1994) 91
Ghannam, M.Y., see Elgamel, H.E. 34 (1994) 237
Glatfelter, T., see Guha, S. 34 (1994) 329
Goetz, M., see Mettler, A. 34 (1994) 533
Green, M.A., S.R. Wenham, C.B. Honsberg and D. Hogg, Transfer of buried contact cell laboratory sequences into commercial production 34 (1994) 83
Green, M.A., see Aberle, A.G. 34 (1994) 149
Green, M.A., see Honsberg, C.B. 34 (1994) 117
Green, M.A., see Wenham, S.R. 34 (1994) 101
Guha, S., J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu, Progress in multijunction amorphous silicon alloy-based solar cells and modules 34 (1994) 329
Guha, S., see Wagner, S. 34 (1994) 373

Hama, T., see Asaoka ,, K. 34 (1994) 465
Hama, T., see Fujikake, S. 34 (1994) 449
Hamakawa, Y., see Ma, W. 34 (1994) 401
Happle, K., see Keppner, H. 34 (1994) 201
Hasegawa, H., see Saitoh, T. 34 (1994) 161
Hasegawa, S., see Nonomura, S. 34 (1994) 549
Hashimoto, H., see Hishikawa, Y. 34 (1994) 303
Hashimoto, T., see Fujii, T. 34 (1994) 409
Hayashi, Y., see Ikeda, T. 34 (1994) 379

Hayashi, Y., see Shimokawa, R. 34 (1994) 277
He, D., N. Okada and I. Shimizu, Carrier transport and structural properties of polysilicon films prepared by layer-by-layer technique 34 (1994) 271
Heiser, G., see Aberle, A.G. 34 (1994) 149
Hirao, T., see Yoshida, A. 34 (1994) 211
Hirose, H., see Takeuchi, S. 34 (1994) 439
Hirose, M., see Deki, H. 34 (1994) 431
Hiruma, T., see Igari, S. 34 (1994) 473
Hiruma, T., see Takahisa, K. 34 (1994) 485
Hishikawa, Y., M. Isomura, S. Okamoto, H. Hashimoto and S. Tsuda, Effects of the i-layer properties and impurity on the performance of a-Si solar cells 34 (1994) 303
Hishikawa, Y., see Sasaki, M. 34 (1994) 541
Hoffman, K., see Guha, S. 34 (1994) 329
Hogg, D., see Green, M.A. 34 (1994) 83
Honsberg, C.B., F. Yun, A. Ebong, M. Taouk, S.R. Wenham and M.A. Green, 685 mV Open-circuit voltage laser grooved silicon solar cell 34 (1994) 117
Honsberg, C.B., see Green, M.A. 34 (1994) 83
Honsberg, C.B., see Wenham, S.R. 34 (1994) 101
Howell, G., see Usher, E. 34 (1994) 73

Ichikawa, Y., Fabrication technology for large-area a-Si solar cells 34 (1994) 321
Ichikawa, Y., see Fujikake, S. 34 (1994) 449
Ichikawa, Y., see Sichanugrist, P. 34 (1994) 415
Igari, S., J. Nose, T. Hiruma, F. Nagamine and K. Fujisawa, Accelerated degradation test method for a-Si PV modules 34 (1994) 473
Igari, S., see Shimokawa, R. 34 (1994) 277
Igari, S., see Takahisa, K. 34 (1994) 485
Ikeda, T., K. Sato, Y. Hayashi, Y. Wakayama, K. Adachi and H. Nishimura, Surface microstructures of ZnO coated SnO_2 : F films 34 (1994) 379
Inamuro, T., see Ohira, T. 34 (1994) 565
Ishida, H., see Yokoi, T. 34 (1994) 517
Ishiguro, N., see Tanaka, H. 34 (1994) 493
Ishihara, T., see Arimoto, S. 34 (1994) 257
Ishii, K., see Shimokawa, R. 34 (1994) 277
Isomura, M., see Hishikawa, Y. 34 (1994) 303
Itoh, M., see Asaoka „ K. 34 (1994) 465
Itoh, M., see Nomoto, K. 34 (1994) 339
Itoh, T., see Nonomura, S. 34 (1994) 549
Itoh, T., see Takeuchi, S. 34 (1994) 439
Izumi, T., see Yoshida, A. 34 (1994) 211
Izumina, M., see Asaoka „ K. 34 (1994) 465
Izumina, M., see Yamamoto, K. 34 (1994) 501

Jang, J., see Park, K.C. 34 (1994) 509
Jean, G., see Usher, E. 34 (1994) 73
Jivacate et al., C., PV development in Thailand 34 (1994) 57
Jun, J.M., see Park, K.C. 34 (1994) 509

Kaneiwa, M., S. Okamoto, I. Yamasaki, M. Nishida and T. Nammori, Cell structures with low–high heterojunction of c-Si and μc-Si : H under rear contact for improvement of efficiencies 34 (1994) 183
Kawama, Y., see Arimoto, S. 34 (1994) 257
Keppner, H., P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess, Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells 34 (1994) 201

Kiess, H., see Keppner, H. 34 (1994) 201
Kim, S.K., see Park, K.C. 34 (1994) 509
Kitagawa, M., see Yoshida, A. 34 (1994) 211
Kobayashi, M., see Yoshioka, K. 34 (1994) 125
Konagai, M., see Wenas, W.W. 34 (1994) 313
Kondo, K., see Yamamoto, K. 34 (1994) 501
Konuma, M., I. Silier, E. Czech and E. Bauser, Semiconductor liquid phase epitaxy for solar cell application 34 (1994) 251
Koyama, M., see Tanaka, H. 34 (1994) 493
Kumabe, H., see Arimoto, S. 34 (1994) 257
Kumagai, K., see Fujimoto, K. 34 (1994) 193
Kumagai, K., see Tamura, F. 34 (1994) 263
Kusian, W., see Popović, P. 34 (1994) 393
Kuwano, Y., The PV Era is coming — the way to GENESIS 34 (1994) 27

Lechner, P., see Bubenzer, A. 34 (1994) 347
Lee, K.H., see Park, K.C. 34 (1994) 509
Leguijt, C., P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi, Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride 34 (1994) 177
Li, L.Q., G.Q. Pan, H.W. Diao, X.B. Liao and Z.P. You, Effects of 1 MeV-electron irradiation on a-Si solar cells 34 (1994) 571
Liao, X.B., see Li, L.Q. 34 (1994) 571
Lim, C.C., see Ma, W. 34 (1994) 401
Lölgen, P., see Leguijt, C. 34 (1994) 177

Ma, W., C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa, Microcrystalline silicon carbide — New useful material for improvement of solar cell performance 34 (1994) 401
Machida, T., see Nakaya, H. 34 (1994) 219
Maruyama, E., see Sayama, K. 34 (1994) 423
Matsukuma, K., K. Morita and T. Warabisako, Performance simulation for bifacial silicon solar cells 34 (1994) 141
Matsunami, H., see Fujii, T. 34 (1994) 409
Matsuno, Y., see Arimoto, S. 34 (1994) 257
Matsuyama, T., T. Baba, T. Takahama, S. Tsuda and S. Nakano, Polycrystalline Si thin-film solar cell prepared by solid phase crystallization (SPC) method 34 (1994) 285
Meier, J., see Keppner, H. 34 (1994) 201
Mertens, R., see Elgamel, H.E. 34 (1994) 237
Metselaar, J.W., see Tao, G. 34 (1994) 359
Metselaar, J.W., see Zeman, M. 34 (1994) 557
Mettler, A., N. Wyrsch, M. Goetz and A. Shah, Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H) 34 (1994) 533
Michiels, P.-P., see Leguijt, C. 34 (1994) 177
Miyashita, T., see Tanaka, H. 34 (1994) 493
Miyazaki, S., see Deki, H. 34 (1994) 431
Morikawa, H., see Arimoto, S. 34 (1994) 257
Morita, K., see Matsukuma, K. 34 (1994) 141
Moriuchi, S., see Nakaya, H. 34 (1994) 219

Muramatsu, S., R. Suzuki, L. Wei and S. Tanigawa, Microvoids in a-Si:H and a-SiGe:H alloys 34 (1994) 525
Murotani, T., see Arimoto, S. 34 (1994) 257

Nagamine, F., see Igari, S. 34 (1994) 473
Nagamine, F., see Shimokawa, R. 34 (1994) 277
Nagata, Y., see Uematsu, T. 34 (1994) 169
Nakagawa, K., see Yoshida, A. 34 (1994) 211
Nakamura, K., see Takahisa, K. 34 (1994) 485
Nakano, S., see Matsuyama, T. 34 (1994) 285
Nakano, S., see Sasaki, M. 34 (1994) 541
Nakano, S., see Sawada, T. 34 (1994) 367
Nakano, S., see Sayama, K. 34 (1994) 423
Nakata, M., see Wagner, S. 34 (1994) 373
Nakaya, H., M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi, Polycrystalline silicon solar cells with V-grooved surface 34 (1994) 219
Nakazawa, S., see Takahisa, K. 34 (1994) 485
Nammori, T., see Kaneiwa, M. 34 (1994) 183
Nijs, J., see Elgamel, H.E. 34 (1994) 237
Ninomiya, K., see Sayama, K. 34 (1994) 423
Nishida, M., see Kaneiwa, M. 34 (1994) 183
Nishida, M., see Nakaya, H. 34 (1994) 219
Nishikawa, H., see Shimokawa, R. 34 (1994) 277
Nishikawa, K., see Yuge, N. 34 (1994) 243
Nishimoto, Y., see Saitoh, T. 34 (1994) 161
Nishimura, E., see Nonomura, S. 34 (1994) 549
Nishimura, H., see Ikeda, T. 34 (1994) 379
Nishiwaki, T., see Nonomura, S. 34 (1994) 549
Nitta, S., see Nonomura, S. 34 (1994) 549
Nitta, S., see Takeuchi, S. 34 (1994) 439
Nomoto, K., H. Saitoh, A. Chida, H. Sannomiya, M. Itoh and Y. Yamamoto, a-Si alloy three-stacked solar cells with high stabilized-efficiency 34 (1994) 339
Nomura, H., see Uematsu, T. 34 (1994) 169
Nonomura, S., T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta, Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS 34 (1994) 549
Nonomura, S., see Takeuchi, S. 34 (1994) 439
Nose, J., see Igari, S. 34 (1994) 473
Nose, J., see Takahisa, K. 34 (1994) 485
Nunoi, T., see Nakaya, H. 34 (1994) 219

Ohira, T., T. Inamuro and T. Adachi, Molecular dynamics simulation of amorphous silicon with Tersoff potential 34 (1994) 565
Ohmura, M., see Deki, H. 34 (1994) 431
Ohnishi, M., see Asaoka ,, K. 34 (1994) 465
Ohsawa, M., see Fujikake, S. 34 (1994) 449
Ohtsuka, H., see Uematsu, T. 34 (1994) 169
Okada, H., see Fujii, T. 34 (1994) 409
Okada, K., see Fukui, K. 34 (1994) 111
Okada, N., see He, D. 34 (1994) 271
Okamoto, H., see Ma, W. 34 (1994) 401
Okamoto, S., see Hishikawa, Y. 34 (1994) 303
Okamoto, S., see Kaneiwa, M. 34 (1994) 183
Okamoto, S., see Sasaki, M. 34 (1994) 541
Okamoto, T., see Yamamoto, K. 34 (1994) 501

Okayasu, Y., see Fujimoto, K. 34 (1994) 193
Okayasu, Y., see Tamura, F. 34 (1994) 263
Ota, H., see Fujikake, S. 34 (1994) 449

Pan, G.Q., see Li, L.Q. 34 (1994) 571
Park, K.C., S.K. Kim, M. Park, J.M. Jun, K.H. Lee and J. Jang, Growth of high quality microcrystalline silicon by layer-by-layer deposition technique 34 (1994) 509
Park, M., see Park, K.C. 34 (1994) 509
Popović, P., J. Furlan and W. Kusian, The wave nature of light in computer analysis of solar cells 34 (1994) 393

Rohatgi, A., Z. Chen, P. Sana, J. Crotty and J. Salami, High efficiency multicrystalline silicon solar cells 34 (1994) 227
Rohatgi, A., see Leguijt, C. 34 (1994) 177
Rübel, H., see Bubenzer, A. 34 (1994) 347
Ruby, D.S., see Basore, P.A. 34 (1994) 91

Sadamoto, M., see Tanaka, H. 34 (1994) 493
Saida, T., see Ma, W. 34 (1994) 401
Saito, I., see Shimokawa, R. 34 (1994) 277
Saitoh, H., see Nomoto, K. 34 (1994) 339
Saitoh, T., Y. Nishimoto and H. Hasegawa, Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy 34 (1994) 161
Saitoh, T., see Uematsu, T. 34 (1994) 169
Saitoh, T., see Yoshioka, K. 34 (1994) 125
Sakaguchi, Y., see Yuge, N. 34 (1994) 243
Sakai, H., Status of amorphous silicon solar cell technologies in Japan 34 (1994) 9
Sakai, H., see Fujikake, S. 34 (1994) 449
Sakai, H., see Sichanugrist, P. 34 (1994) 415
Salami, J., see Rohatgi, A. 34 (1994) 227
Sameshima, K., see Fujii, T. 34 (1994) 409
Sana, P., see Rohatgi, A. 34 (1994) 227
Sannomiya, H., see Nomoto, K. 34 (1994) 339
Sarro, P.M., see Leguijt, C. 34 (1994) 177
Sasaki, M., S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano, Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements 34 (1994) 541
Sasaki, T., see Sichanugrist, P. 34 (1994) 415
Sato, K., see Ikeda, T. 34 (1994) 379
Sawada, T., N. Terada, T. Takahama, H. Tarui, M. Tanaka, S. Tsuda and S. Nakano, Numerical approach for high-efficiency a-Si solar cells 34 (1994) 367
Sayama, K., A. Terakawa, M. Shima, E. Maruyama, K. Ninomiya, H. Tarui, S. Tsuda and S. Nakano, Control of a-SiGe:H film quality with regard to its composition 34 (1994) 423
Schade, H., see Bubenzer, A. 34 (1994) 347
Schock, H.W., Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe 34 (1994) 19
Schropp, R.E.I., M.B. von der Linden, J. Daey Ouwens and H. de Gooijer, Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells 34 (1994) 455
Schubert, W.K., see Basore, P.A. 34 (1994) 91
Shah, A., see Keppner, H. 34 (1994) 201
Shah, A., see Mettler, A. 34 (1994) 533

Shima, K., see Fujimoto, K. 34 (1994) 193
Shima, M., see Sayama, K. 34 (1994) 423
Shimizu, I., see He, D. 34 (1994) 271
Shimizu, I., see Yokoi, T. 34 (1994) 517
Shimokawa, R., K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari, Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate 34 (1994) 277
Shimokawa, R., see Asaoka „ K. 34 (1994) 465
Shirasawa, K., see Fukui, K. 34 (1994) 111
Sichanugrist, P., T. Sasaki, A. Asano, Y. Ichikawa and H. Sakai, Amorphous silicon oxide and its application to metal/n-i-p/ITO type a-Si solar cells 34 (1994) 415
Silier, I., see Konuma, M. 34 (1994) 251
Sinke, W.C., see Leguijt, C. 34 (1994) 177
Smole, F., M. Topič and J. Furlan, Amorphous silicon solar cell computer model incorporating the effects of TCO/a-Si:C:H junction 34 (1994) 385
Sogawa, Y., see Fujimoto, K. 34 (1994) 193
Solntsev, S., see Zeman, M. 34 (1994) 557
Song, J., Recent progress in national photovoltaic project in Korea 34 (1994) 51
Sørensen, B., Model optimization of photovoltaic cells 34 (1994) 133
Steeman, R.A., see Leguijt, C. 34 (1994) 177
Stone, J.L., SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States 34 (1994) 41
Sugiyama, Y., see Takahisa, K. 34 (1994) 485
Suzuki, A., see Yoshioka, K. 34 (1994) 125
Suzuki, R., see Muramatsu, S. 34 (1994) 525
Suzuki, T., see Yamamoto, K. 34 (1994) 501
Suzuki, Y., see Asaoka „ K. 34 (1994) 465

Takahama, T., see Matsuyama, T. 34 (1994) 285
Takahama, T., see Sawada, T. 34 (1994) 367
Takahashi, H., see Fukui, K. 34 (1994) 111
Takahashi, K., see Wenas, W.W. 34 (1994) 313
Takahashi, T., see Shimokawa, R. 34 (1994) 277
Takahisa, K., K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma, Long-term reliability of amorphous silicon solar cells 34 (1994) 485
Takayama, M., see Fukui, K. 34 (1994) 111
Takeda, Y., see Nakaya, H. 34 (1994) 219
Takeuchi, S., H. Hirose, S. Nitta, T. Itoh and S. Nonomura, Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H 34 (1994) 439
Tamura, F., Y. Okayasu and K. Kumagai, Fabrication of poly-crystalline silicon films using plasma spray method 34 (1994) 263
Tanaka, H., N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda, Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method 34 (1994) 493
Tanaka, M., see Sawada, T. 34 (1994) 367
Tanigawa, S., see Muramatsu, S. 34 (1994) 525
Tao, G., M. Zeman and J.W. Metselaar, Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates 34 (1994) 359
Taouk, M., see Honsberg, C.B. 34 (1994) 117
Tarui, H., see Sawada, T. 34 (1994) 367
Tarui, H., see Sayama, K. 34 (1994) 423
Tawada, Y., see Asaoka „ K. 34 (1994) 465
Tawada, Y., see Yamamoto, K. 34 (1994) 501

Terada, N., see Sawada, T. 34 (1994) 367
Terakawa, A., see Sayama, K. 34 (1994) 423
Terashima, H., see Yuge, N. 34 (1994) 243
Tojo, F., see Yoshida, A. 34 (1994) 211
Tonegawa, T., see Nakaya, H. 34 (1994) 219
Topič, M., see Smole, F. 34 (1994) 385
Torres, P., see Keppner, H. 34 (1994) 201
Tsuda, S., see Hishikawa, Y. 34 (1994) 303
Tsuda, S., see Matsuyama, T. 34 (1994) 285
Tsuda, S., see Sasaki, M. 34 (1994) 541
Tsuda, S., see Sawada, T. 34 (1994) 367
Tsuda, S., see Sayama, K. 34 (1994) 423

Uematsu, T., Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh, Characterization of surface recombination velocity at Si solar cell surface under high injection level 34 (1994) 169
Usher, E., G. Jean and G. Howell, The use of photovoltaics in a northern climate 34 (1994) 73

Van Overstraeten, R., see Elgamel, H.E. 34 (1994) 237
Vasanth, K., see Wagner, S. 34 (1994) 373
Verhoef, L.A., see Leguijt, C. 34 (1994) 177
Vinckier, C., see Elgamel, H.E. 34 (1994) 237
von der Linden, M.B., see Schropp, R.E.I. 34 (1994) 455

Wagner, S., K. Vasanth, M. Nakata, J. Yang and S. Guha, Measuring and modelling of a-Si,Ge:H solar cells 34 (1994) 373
Wakayama, Y., see Ikeda, T. 34 (1994) 379
Warabisako, T., see Matsukuma, K. 34 (1994) 141
Warabisako, T., see Uematsu, T. 34 (1994) 169
Watanabe, H., see Fukui, K. 34 (1994) 111
Wei, L., see Muramatsu, S. 34 (1994) 525
Wenas, W.W., A. De, A. Yamada, M. Konagai and K. Takahashi, Optimization of ZnO for front and rear contacts in a-Si solar cells 34 (1994) 313
Wenham, S.R., C.B. Honsberg and M.A. Green, Buried Contact Silicon Solar Cells 34 (1994) 101
Wenham, S.R., see Green, M.A. 34 (1994) 83
Wenham, S.R., see Honsberg, C.B. 34 (1994) 117
Willeke, G., see Keppner, H. 34 (1994) 201
Willemen, J.A., see Zeman, M. 34 (1994) 557
Wyrsch, N., see Mettler, A. 34 (1994) 533

Xu, X., see Guha, S. 34 (1994) 329

Yamada, A., see Wenas, W.W. 34 (1994) 313
Yamaguchi, M., see Yamamoto, K. 34 (1994) 501
Yamamoto, K., T. Suzuki, K. Kondo, T. Okamoto, M. Yamaguchi, M. Izumina and Y. Tawada, Low temperature Si crystal growth by alternating deposition and hydrogen etching sequences and its application to the p-layer of a-Si:H solar cells 34 (1994) 501
Yamamoto, Y., see Nomoto, K. 34 (1994) 339
Yamasaki, I., see Kaneiwa, M. 34 (1994) 183
Yanagawa, N., see Tanaka, H. 34 (1994) 493
Yang, J., see Guha, S. 34 (1994) 329

Yang, J., see Wagner, S. 34 (1994) 373
Yokoi, T., M. Azuma, H. Ishida and I. Shimizu, Fabrication of stable hydrogenated amorphous silicon from SiH_2Cl_2 by ECR-hydrogen-plasma 34 (1994) 517
Yoshida, A., M. Kitagawa, F. Tojo, N. Egashira, K. Nakagawa, T. Izumi and T. Hirao, Hydrogen, fluorine ion implantation effects on polycrystalline silicon grain boundaries 34 (1994) 211
Yoshida, K., see Fujii, T. 34 (1994) 409
Yoshimoto, M., see Fujii, T. 34 (1994) 409
Yoshioka, K., K. Endoh, M. Kobayashi, A. Suzuki and T. Saitoh, Design and properties of a refractive static concentrator module 34 (1994) 125
You, Z.P., see Li, L.Q. 34 (1994) 571
Yuge, N., H. Baba, Y. Sakaguchi, K. Nishikawa, H. Terashima and F. Aratani, Purification of metallurgical silicon up to solar grade 34 (1994) 243
Yun, F., see Honsberg, C.B. 34 (1994) 117

Zeman, M., J.A. Willemen, S. Solntsev and J.W. Metselaar, Extraction of amorphous silicon solar cell parameters by inverse modelling 34 (1994) 557
Zeman, M., see Tao, G. 34 (1994) 359

ELSEVIER

Solar Energy Materials and Solar Cells 34 (1994) 591–606

Solar Energy Materials and Solar Cells

Subject Index Volume 34

Amorphous materials, general

Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method, H. Tanaka, N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda 34 (1994) 493

Amorphous semiconductors

Control of a-SiGe:H film quality with regard to its composition, K. Sayama, A. Terakawa, M. Shima, E. Maruyama, K. Ninomiya, H. Tarui, S. Tsuda and S. Nakano 34 (1994) 423

Growth of high quality microcrystalline silicon by layer-by-layer deposition technique, K.C. Park, S.K. Kim, M. Park, J.M. Jun, K.H. Lee and J. Jang 34 (1994) 509

Amorphous silicon, hydrogenated amorphous Si, general material properties

Single-junction a-Si solar cells with over 13% efficiency, Y. Ashida 34 (1994) 291

Effects of the i-layer properties and impurity on the performance of a-Si solar cells, Y. Hishikawa, M. Isomura, S. Okamoto, H. Hashimoto and S. Tsuda 34 (1994) 303

Fabrication technology for large-area a-Si solar cells, Y. Ichikawa 34 (1994) 321

Progress in multijunction amorphous silicon alloy-based solar cells and modules, S. Guha, J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu 34 (1994) 329

Amorphous silicon oxide and its application to metal/n-i-p/ITO type a-Si solar cells, P. Sichanugrist, T. Sasaki, A. Asano, Y. Ichikawa and H. Sakai 34 (1994) 415

Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells, H. Deki, M. Ohmura, S. Miyazaki and M. Hirose 34 (1994) 431

Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H, S. Takeuchi, H. Hirose, S. Nitta, T. Itoh and S. Nonomura 34 (1994) 439

Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method, H. Tanaka, N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda 34 (1994) 493

Growth of high quality microcrystalline silicon by layer-by-layer deposition technique, K.C. Park, S.K. Kim, M. Park, J.M. Jun, K.H. Lee and J. Jang 34 (1994) 509

Fabrication of stable hydrogenated amorphous silicon from SiH_2Cl_2 by ECR-hydrogen-plasma, T. Yokoi, M. Azuma, H. Ishida and I. Shimizu 34 (1994) 517

Microvoids in a-Si:H and a-SiGe:H alloys, S. Muramatsu, R. Suzuki, L. Wei and S. Tanigawa 34 (1994) 525

Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H), A. Mettler, N. Wyrsch, M. Goetz and A. Shah 34 (1994) 533

Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements, M. Sasaki, S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano 34 (1994) 541
Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS, S. Nonomura, T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta 34 (1994) 549
Extraction of amorphous silicon solar cell parameters by inverse modelling, M. Zeman, J.A. Willemen, S. Solntsev and J.W. Metselaar 34 (1994) 557
Effects of 1 MeV-electron irradiation on a-Si solar cells, L.Q. Li, G.Q. Pan, H.W. Diao, X.B. Liao and Z.P. You 34 (1994) 571
Molecular dynamics simulation of amorphous silicon with Tersoff potential, T. Ohira, T. Inamuro and T. Adachi 34 (1994) 565

Amorphous silicon, hydrogenated amorphous Si, general solar cell properties and device physics

Status of amorphous silicon solar cell technologies in Japan, H. Sakai 34 (1994) 9
The PV Era is coming — the way to GENESIS, Y. Kuwano 34 (1994) 27
Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells, H. Keppner, P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess 34 (1994) 201
Single-junction a-Si solar cells with over 13% efficiency, Y. Ashida 34 (1994) 291
Effects of the i-layer properties and impurity on the performance of a-Si solar cells, Y. Hishikawa, M. Isomura, S. Okamoto, H. Hashimoto and S. Tsuda 34 (1994) 303
Optimization of ZnO for front and rear contacts in a-Si solar cells, W.W. Wenas, A. De, A. Yamada, M. Konagai and K. Takahashi 34 (1994) 313
Fabrication technology for large-area a-Si solar cells, Y. Ichikawa 34 (1994) 321
a-Si alloy three-stacked solar cells with high stabilized-efficiency, K. Nomoto, H. Saitoh, A. Chida, H. Sannomiya, M. Itoh and Y. Yamamoto 34 (1994) 339
Process technology for mass production of large-area a-Si solar modules, A. Bubenzer, P. Lechner, H. Schade and H. Rübel 34 (1994) 347
Numerical approach for high-efficiency a-Si solar cells, T. Sawada, N. Terada, T. Takahama, H. Tarui, M. Tanaka, S. Tsuda and S. Nakano 34 (1994) 367
Measuring and modelling of a-Si,Ge:H solar cells, S. Wagner, K. Vasanth, M. Nakata, J. Yang and S. Guha 34 (1994) 373
Amorphous silicon solar cell computer model incorporating the effects of TCO/a-Si:C:H junction, F. Smole, M. Topič and J. Furlan 34 (1994) 385
The wave nature of light in computer analysis of solar cells, P. Popović, J. Furlan and W. Kusian 34 (1994) 393
Microcrystalline silicon carbide — New useful material for improvement of solar cell performance, W. Ma, C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa 34 (1994) 401
Control of a-SiGe:H film quality with regard to its composition, K. Sayama, A. Terakawa, M. Shima, E. Maruyama, K. Ninomiya, H. Tarui, S. Tsuda and S. Nakano 34 (1994) 423
Light-induced recovery of a-Si solar cells, S. Fujikake, H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai 34 (1994) 449
Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells, R.E.I. Schropp, M.B. von der Linden, J. Daey Ouwens and H. de Gooijer 34 (1994) 455
Long-term reliability of amorphous silicon solar cells, K. Takahisa, K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma 34 (1994) 485
Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method, H. Tanaka, N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda 34 (1994) 493

Low temperature Si crystal growth by alternating deposition and hydrogen etching sequences and its application to the p-layer of a-Si:H solar cells, K. Yamamoto, T. Suzuki, K. Kondo, T. Okamoto, M. Yamaguchi, M. Izumina and Y. Tawada 34 (1994) 501
Growth of high quality microcrystalline silicon by layer-by-layer deposition technique, K.C. Park, S.K. Kim, M. Park, J.M. Jun, K.H. Lee and J. Jang 34 (1994) 509
Microvoids in a-Si:H and a-SiGe:H alloys, S. Muramatsu, R. Suzuki, L. Wei and S. Tanigawa 34 (1994) 525
Extraction of amorphous silicon solar cell parameters by inverse modelling, M. Zeman, J.A. Willemen, S. Solntsev and J.W. Metselaar 34 (1994) 557
Effects of 1 MeV-electron irradiation on a-Si solar cells, L.Q. Li, G.Q. Pan, H.W. Diao, X.B. Liao and Z.P. You 34 (1994) 571

Amorphous silicon, hydrogenated amorphous Si, optical studies in stability

Single-junction a-Si solar cells with over 13% efficiency, Y. Ashida 34 (1994) 291
Effects of the i-layer properties and impurity on the performance of a-Si solar cells, Y. Hishikawa, M. Isomura, S. Okamoto, H. Hashimoto and S. Tsuda 34 (1994) 303
Light-induced recovery of a-Si solar cells, S. Fujikake, H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai 34 (1994) 449
Accelerated degradation test method for a-Si PV modules, S. Igari, J. Nose, T. Hiruma, F. Nagamine and K. Fujisawa 34 (1994) 473
Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method, H. Tanaka, N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda 34 (1994) 493
Fabrication of stable hydrogenated amorphous silicon from SiH_2Cl_2 by ECR-hydrogen-plasma, T. Yokoi, M. Azuma, H. Ishida and I. Shimizu 34 (1994) 517
Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements, M. Sasaki, S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano 34 (1994) 541

Amorphous silicon, hydrogenated amorphous Si alloys: Cl, O, etc.

Fabrication technology for large-area a-Si solar cells, Y. Ichikawa 34 (1994) 321
Amorphous silicon oxide and its application to metal/n-i-p/ITO type a-Si solar cells, P. Sichanugrist, T. Sasaki, A. Asano, Y. Ichikawa and H. Sakai 34 (1994) 415
Control of a-SiGe:H film quality with regard to its composition, K. Sayama, A. Terakawa, M. Shima, E. Maruyama, K. Ninomiya, H. Tarui, S. Tsuda and S. Nakano 34 (1994) 423
Microvoids in a-Si:H and a-SiGe:H alloys, S. Muramatsu, R. Suzuki, L. Wei and S. Tanigawa 34 (1994) 525
Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS, S. Nonomura, T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta 34 (1994) 549

Amorphous silicon carbide alloys

Single-junction a-Si solar cells with over 13% efficiency, Y. Ashida 34 (1994) 291
Microcrystalline silicon carbide — New useful material for improvement of solar cell performance, W. Ma, C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa 34 (1994) 401
Characterization of hydrogenated amorphous silicon–carbon films deposited by hybrid-plasma CVD, T. Fujii, K. Sameshima, H. Okada, K. Yoshida, T. Hashimoto, M. Yoshimoto, T. Fuyuki and H. Matsunami 34 (1994) 409

Fabricating high performance a-Si solar cells by alternately repeating deposition and hydrogen plasma treatment method, H. Tanaka, N. Ishiguro, T. Miyashita, N. Yanagawa, M. Sadamoto, M. Koyama, Y. Ashida and N. Fukuda 34 (1994) 493

Amorphous silicon nitride

Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H, S. Takeuchi, H. Hirose, S. Nitta, T. Itoh and S. Nonomura 34 (1994) 439
Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS, S. Nonomura, T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta 34 (1994) 549

Annealing

Characterization of surface recombination velocity at Si solar cell surface under high injection level, T. Uematsu, Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh 34 (1994) 169
Light-induced recovery of a-Si solar cells, S. Fujikake, H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai 34 (1994) 449

Antireflection coatings

Polycrystalline silicon solar cells with V-grooved surface, H. Nakaya, M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi 34 (1994) 219
High efficiency multicrystalline silicon solar cells, A. Rohatgi, Z. Chen, P. Sana, J. Crotty and J. Salami 34 (1994) 227

Carrier Lifetime

Characterization of surface recombination velocity at Si solar cell surface under high injection level, T. Uematsu, Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh 34 (1994) 169
Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride, C. Leguijt, P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi 34 (1994) 177

Chemical vapour deposition

High efficiency silicon solar cells by plasma-CVD method, K. Fujimoto, Y. Sogawa, K. Shima, Y. Okayasu and K. Kumagai 34 (1994) 193
Optimization of ZnO for front and rear contacts in a-Si solar cells, W.W. Wenas, A. De, A. Yamada, M. Konagai and K. Takahashi 34 (1994) 313
Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells, H. Deki, M. Ohmura, S. Miyazaki and M. Hirose 34 (1994) 431
Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements, M. Sasaki, S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano 34 (1994) 541
Molecular dynamics simulation of amorphous silicon with Tersoff potential, T. Ohira, T. Inamuro and T. Adachi 34 (1994) 565

Conversion efficiency

Status of amorphous silicon solar cell technologies in Japan, H. Sakai 34 (1994) 9

SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States, J.L. Stone 34 (1994) 41
Buried Contact Silicon Solar Cells, S.R. Wenham, C.B. Honsberg and M.A. Green 34 (1994) 101
Cell structures with low–high heterojunction of c-Si and μc-Si:H under rear contact for improvement of efficiencies, M. Kaneiwa, S. Okamoto, I. Yamasaki, M. Nishida and T. Nammori 34 (1994) 183
High efficiency silicon solar cells by plasma-CVD method, K. Fujimoto, Y. Sogawa, K. Shima, Y. Okayasu and K. Kumagai 34 (1994) 193
Polycrystalline silicon solar cells with V-grooved surface, H. Nakaya, M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi 34 (1994) 219
Boosting the efficiency of solar cells fabricated on electromagnetic cold crucible cast multicrystalline silicon by means of hydrogen passivation, H.E. Elgamel, M.Y. Ghannam, C. Vinckier, J. Nijs, R. Mertens and R. Van Overstraeten 34 (1994) 237
High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure, S. Arimoto, H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani 34 (1994) 257
Effects of the i-layer properties and impurity on the performance of a-Si solar cells, Y. Hishikawa, M. Isomura, S. Okamoto, H. Hashimoto and S. Tsuda 34 (1994) 303
a-Si alloy three-stacked solar cells with high stabilized-efficiency, K. Nomoto, H. Saitoh, A. Chida, H. Sannomiya, M. Itoh and Y. Yamamoto 34 (1994) 339
Effects of 1 MeV-electron irradiation on a-Si solar cells, L.Q. Li, G.Q. Pan, H.W. Diao, X.B. Liao and Z.P. You 34 (1994) 571

Concentrators

Design and properties of a refractive static concentrator module, K. Yoshioka, K. Endoh, M. Kobayashi, A. Suzuki and T. Saitoh 34 (1994) 125

Copper gallium indium selenide, $CuGa_xIn_{1-x}Se$

Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe, H.W. Schock 34 (1994) 19

Copper indium selenide, $CuInSe_2$

Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe, H.W. Schock 34 (1994) 19

Copper indium sulfide, $CuInS_2$

Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe, H.W. Schock 34 (1994) 19

Crystalline silicon, cells and related coatings

Transfer of buried contact cell laboratory sequences into commercial production, M.A. Green, S.R. Wenham, C.B. Honsberg and D. Hogg 34 (1994) 83
Simplified high-efficiency silicon cell processing, P.A. Basore, J.M. Gee, M.E. Buck, W.K. Schubert and D.S. Ruby 34 (1994) 91
Large-area high-efficiency single crystalline silicon solar cells, K. Fukui, Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe 34 (1994) 111

Model optimization of photovoltaic cells, B. Sørensen 34 (1994) 133
Performance simulation for bifacial silicon solar cells, K. Matsukuma, K. Morita and T. Warabisako 34 (1994) 141
Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride, C. Leguijt, P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi 34 (1994) 177
High efficiency silicon solar cells by plasma-CVD method, K. Fujimoto, Y. Sogawa, K. Shima, Y. Okayasu and K. Kumagai 34 (1994) 193
Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells, H. Keppner, P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess 34 (1994) 201
Semiconductor liquid phase epitaxy for solar cell application, M. Konuma, I. Silier, E. Czech and E. Bauser 34 (1994) 251
Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate, R. Shimokawa, K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari 34 (1994) 277

Crystalline silicon, MIS cells

Low temperature Si crystal growth by alternating deposition and hydrogen etching sequences and its application to the p-layer of a-Si:H solar cells, K. Yamamoto, T. Suzuki, K. Kondo, T. Okamoto, M. Yamaguchi, M. Izumina and Y. Tawada 34 (1994) 501

Crystalline silicon, production

Transfer of buried contact cell laboratory sequences into commercial production, M.A. Green, S.R. Wenham, C.B. Honsberg and D. Hogg 34 (1994) 83
Purification of metallurgical silicon up to solar grade, N. Yuge, H. Baba, Y. Sakaguchi, K. Nishikawa, H. Terashima and F. Aratani 34 (1994) 243

Defect electron energy states

Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells, R.E.I. Schropp, M.B. von der Linden, J. Daey Ouwens and H. de Gooijer 34 (1994) 455
Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H), A. Mettler, N. Wyrsch, M. Goetz and A. Shah 34 (1994) 533

Efficiency

Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe, H.W. Schock 34 (1994) 19
Recent progress in national photovoltaic project in Korea, J. Song 34 (1994) 51
Transfer of buried contact cell laboratory sequences into commercial production, M.A. Green, S.R. Wenham, C.B. Honsberg and D. Hogg 34 (1994) 83
Model optimization of photovoltaic cells, B. Sørensen 34 (1994) 133
Progress in multijunction amorphous silicon alloy-based solar cells and modules, S. Guha, J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu 34 (1994) 329
Long-term reliability of amorphous silicon solar cells, K. Takahisa, K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma 34 (1994) 485

Electrical properties

Numerical approach for high-efficiency a-Si solar cells, T. Sawada, N. Terada, T. Takahama, H. Tarui, M. Tanaka, S. Tsuda and S. Nakano 34 (1994) 367
The wave nature of light in computer analysis of solar cells, P. Popović, J. Furlan and W. Kusian 34 (1994) 393
Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells, H. Deki, M. Ohmura, S. Miyazaki and M. Hirose 34 (1994) 431

Electron–hole recombination

Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy, T. Saitoh, Y. Nishimoto and H. Hasegawa 34 (1994) 161

Energy gap

Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements, M. Sasaki, S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano 34 (1994) 541

Environmental degradation and testing

Status of amorphous silicon solar cell technologies in Japan, H. Sakai 34 (1994) 9
Accelerated degradation test method for a-Si PV modules, S. Igari, J. Nose, T. Hiruma, F. Nagamine and K. Fujisawa 34 (1994) 473
Long-term reliability of amorphous silicon solar cells, K. Takahisa, K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma 34 (1994) 485

Fluorine

Hydrogen, fluorine ion implantation effects on polycrystalline silicon grain boundaries, A. Yoshida, M. Kitagawa, F. Tojo, N. Egashira, K. Nakagawa, T. Izumi and T. Hirao 34 (1994) 211

Gallium arsenide and gallium aluminium arsenide, GaAs, $Ga_{1-x}Al_xAs$

Semiconductor liquid phase epitaxy for solar cell application, M. Konuma, I. Silier, E. Czech and E. Bauser 34 (1994) 251

Ge–Si alloys

Measuring and modelling of a-Si,Ge:H solar cells, S. Wagner, K. Vasanth, M. Nakata, J. Yang and S. Guha 34 (1994) 373
Microvoids in a-Si:H and a-SiGe:H alloys, S. Muramatsu, R. Suzuki, L. Wei and S. Tanigawa 34 (1994) 525

Hydrogen

Characterization of surface recombination velocity at Si solar cell surface under high injection level, T. Uematsu, Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh 34 (1994) 169

Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride, C. Leguijt, P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi 34 (1994) 177
Hydrogen, fluorine ion implantation effects on polycrystalline silicon grain boundaries, A. Yoshida, M. Kitagawa, F. Tojo, N. Egashira, K. Nakagawa, T. Izumi and T. Hirao 34 (1994) 211
High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure, S. Arimoto, H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani 34 (1994) 257

I–V characteristics

Polycrystalline silicon solar cells with V-grooved surface, H. Nakaya, M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi 34 (1994) 219
Progress in multijunction amorphous silicon alloy-based solar cells and modules, S. Guha, J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu 34 (1994) 329
Effects of 1 MeV-electron irradiation on a-Si solar cells, L.Q. Li, G.Q. Pan, H.W. Diao, X.B. Liao and Z.P. You 34 (1994) 571

Interfaces

Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy, T. Saitoh, Y. Nishimoto and H. Hasegawa 34 (1994) 161
Amorphous silicon solar cell computer model incorporating the effects of TCO/a-Si:C:H junction, F. Smole, M. Topič and J. Furlan 34 (1994) 385
Microcrystalline silicon carbide — New useful material for improvement of solar cell performance, W. Ma, C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa 34 (1994) 401
Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells, R.E.I. Schropp, M.B. von der Linden, J. Daey Ouwens and H. de Gooijer 34 (1994) 455

Light absorption

Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates, G. Tao, M. Zeman and J.W. Metselaar 34 (1994) 359
The wave nature of light in computer analysis of solar cells, P. Popović, J. Furlan and W. Kusian 34 (1994) 393

Light trapping (concentration)

Polycrystalline silicon solar cells with V-grooved surface, H. Nakaya, M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi 34 (1994) 219
Semiconductor liquid phase epitaxy for solar cell application, M. Konuma, I. Silier, E. Czech and E. Bauser 34 (1994) 251
Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates, G. Tao, M. Zeman and J.W. Metselaar 34 (1994) 359

Materials issues, general

Recent progress in national photovoltaic project in Korea, J. Song 34 (1994) 51

Measurements, absorptance, emittance and reflectance

Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate, R. Shimokawa, K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari 34 (1994) 277

Minority carriers

Cell structures with low–high heterojunction of c-Si and μc-Si:H under rear contact for improvement of efficiencies, M. Kaneiwa, S. Okamoto, I. Yamasaki, M. Nishida and T. Nammori 34 (1994) 183

Mirrors

Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H, S. Takeuchi, H. Hirose, S. Nitta, T. Itoh and S. Nonomura 34 (1994) 439

MOCVD

Optimization of ZnO for front and rear contacts in a-Si solar cells, W.W. Wenas, A. De, A. Yamada, M. Konagai and K. Takahashi 34 (1994) 313

Open-circuit voltage

Buried Contact Silicon Solar Cells, S.R. Wenham, C.B. Honsberg and M.A. Green 34 (1994) 101
685 mV Open-circuit voltage laser grooved silicon solar cell, C.B. Honsberg, F. Yun, A. Ebong, M. Taouk, S.R. Wenham and M.A. Green 34 (1994) 117
Cell structures with low–high heterojunction of c-Si and μc-Si:H under rear contact for improvement of efficiencies, M. Kaneiwa, S. Okamoto, I. Yamasaki, M. Nishida and T. Nammori 34 (1994) 183
Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells, H. Keppner, P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess 34 (1994) 201

Optical properties

Design and properties of a refractive static concentrator module, K. Yoshioka, K. Endoh, M. Kobayashi, A. Suzuki and T. Saitoh 34 (1994) 125
Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate, R. Shimokawa, K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari 34 (1994) 277
Numerical approach for high-efficiency a-Si solar cells, T. Sawada, N. Terada, T. Takahama, H. Tarui, M. Tanaka, S. Tsuda and S. Nakano 34 (1994) 367
Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells, H. Deki, M. Ohmura, S. Miyazaki and M. Hirose 34 (1994) 431
Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H, S. Takeuchi, H. Hirose, S. Nitta, T. Itoh and S. Nonomura 34 (1994) 439
Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H), A. Mettler, N. Wyrsch, M. Goetz and A. Shah 34 (1994) 533

Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS, S. Nonomura, T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta 34 (1994) 549

p–n heterojunctions

Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells, H. Keppner, P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess 34 (1994) 201

Passivation

Simplified high-efficiency silicon cell processing, P.A. Basore, J.M. Gee, M.E. Buck, W.K. Schubert and D.S. Ruby 34 (1994) 91

Large-area high-efficiency single crystalline silicon solar cells, K. Fukui, Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe 34 (1994) 111

Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy, T. Saitoh, Y. Nishimoto and H. Hasegawa 34 (1994) 161

Characterization of surface recombination velocity at Si solar cell surface under high injection level, T. Uematsu, Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh 34 (1994) 169

Passivation properties of amorphous and microcrystalline silicon layers deposited by VHF-GD for crystalline silicon solar cells, H. Keppner, P. Torres, R. Flückiger, J. Meier, A. Shah, C. Fortmann, P. Fath, G. Willeke, K. Happle and H. Kiess 34 (1994) 201

Hydrogen, fluorine ion implantation effects on polycrystalline silicon grain boundaries, A. Yoshida, M. Kitagawa, F. Tojo, N. Egashira, K. Nakagawa, T. Izumi and T. Hirao 34 (1994) 211

High efficiency multicrystalline silicon solar cells, A. Rohatgi, Z. Chen, P. Sana, J. Crotty and J. Salami 34 (1994) 227

Boosting the efficiency of solar cells fabricated on electromagnetic cold crucible cast multicrystalline silicon by means of hydrogen passivation, H.E. Elgamel, M.Y. Ghannam, C. Vinckier, J. Nijs, R. Mertens and R. Van Overstraeten 34 (1994) 237

High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure, S. Arimoto, H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani 34 (1994) 257

Photoconductivity

High efficiency multicrystalline silicon solar cells, A. Rohatgi, Z. Chen, P. Sana, J. Crotty and J. Salami 34 (1994) 227

Characterization of hydrogenated amorphous silicon–carbon films deposited by hybrid-plasma CVD, T. Fujii, K. Sameshima, H. Okada, K. Yoshida, T. Hashimoto, M. Yoshimoto, T. Fuyuki and H. Matsunami 34 (1994) 409

Narrow-bandgap a-Ge:H/a-Si:H multilayers for amorphous silicon-based solar cells, H. Deki, M. Ohmura, S. Miyazaki and M. Hirose 34 (1994) 431

Photocurrent

Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate, R. Shimokawa, K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari 34 (1994) 277

Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H), A. Mettler, N. Wyrsch, M. Goetz and A. Shah 34 (1994) 533
Characterization of the defect density and band tail of an a-Si:H i-layer for solar cells by improved CPM measurements, M. Sasaki, S. Okamoto, Y. Hishikawa, S. Tsuda and S. Nakano 34 (1994) 541

Photoluminescence

Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy, T. Saitoh, Y. Nishimoto and H. Hasegawa 34 (1994) 161

Photovoltaic effects

SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States, J.L. Stone 34 (1994) 41
Promoting photovoltaic electricity usage in developing countries — Experience from Ghana, K.G. Adanu 34 (1994) 67
High efficiency multicrystalline silicon solar cells, A. Rohatgi, Z. Chen, P. Sana, J. Crotty and J. Salami 34 (1994) 227

Photovoltaics, general properties and types

PV development in Thailand, C. Jivacate et al. 34 (1994) 57
Promoting photovoltaic electricity usage in developing countries — Experience from Ghana, K.G. Adanu 34 (1994) 67
The use of photovoltaics in a northern climate, E. Usher, G. Jean and G. Howell 34 (1994) 73
Buried Contact Silicon Solar Cells, S.R. Wenham, C.B. Honsberg and M.A. Green 34 (1994) 101
685 mV Open-circuit voltage laser grooved silicon solar cell, C.B. Honsberg, F. Yun, A. Ebong, M. Taouk, S.R. Wenham and M.A. Green 34 (1994) 117

Plasma CVD coatings

Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride, C. Leguijt, P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi 34 (1994) 177

Plasma deposited coatings

Fabrication of poly-crystalline silicon films using plasma spray method, F. Tamura, Y. Okayasu and K. Kumagai 34 (1994) 263

Polycrystalline silicon

The PV Era is coming — the way to GENESIS, Y. Kuwano 34 (1994) 27
Hydrogen, fluorine ion implantation effects on polycrystalline silicon grain boundaries, A. Yoshida, M. Kitagawa, F. Tojo, N. Egashira, K. Nakagawa, T. Izumi and T. Hirao 34 (1994) 211

Polycrystalline silicon solar cells with V-grooved surface, H. Nakaya, M. Nishida, Y. Takeda, S. Moriuchi, T. Tonegawa, T. Machida and T. Nunoi 34 (1994) 219
High efficiency multicrystalline silicon solar cells, A. Rohatgi, Z. Chen, P. Sana, J. Crotty and J. Salami 34 (1994) 227
Boosting the efficiency of solar cells fabricated on electromagnetic cold crucible cast multicrystalline silicon by means of hydrogen passivation, H.E. Elgamel, M.Y. Ghannam, C. Vinckier, J. Nijs, R. Mertens and R. Van Overstraeten 34 (1994) 237
Purification of metallurgical silicon up to solar grade, N. Yuge, H. Baba, Y. Sakaguchi, K. Nishikawa, H. Terashima and F. Aratani 34 (1994) 243
High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure, S. Arimoto, H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani 34 (1994) 257
Fabrication of poly-crystalline silicon films using plasma spray method, F. Tamura, Y. Okayasu and K. Kumagai 34 (1994) 263
Polycrystalline Si thin-film solar cell prepared by solid phase crystallization (SPC) method, T. Matsuyama, T. Baba, T. Takahama, S. Tsuda and S. Nakano 34 (1994) 285
Microcrystalline silicon carbide — New useful material for improvement of solar cell performance, W. Ma, C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa 34 (1994) 401

Reflectivity

Optical properties of random amorphous multilayers a-Si:H/a-Si_3N_{4+x}:H, S. Takeuchi, H. Hirose, S. Nitta, T. Itoh and S. Nonomura 34 (1994) 439

Reliability

SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States, J.L. Stone 34 (1994) 41
The use of photovoltaics in a northern climate, E. Usher, G. Jean and G. Howell 34 (1994) 73
Light-induced recovery of a-Si solar cells, S. Fujikake, H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai 34 (1994) 449
Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells, R.E.I. Schropp, M.B. von der Linden, J. Daey Ouwens and H. de Gooijer 34 (1994) 455
Accelerated degradation test method for a-Si PV modules, S. Igari, J. Nose, T. Hiruma, F. Nagamine and K. Fujisawa 34 (1994) 473
Long-term reliability of amorphous silicon solar cells, K. Takahisa, K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma 34 (1994) 485

Semiconductor device models

Performance simulation for bifacial silicon solar cells, K. Matsukuma, K. Morita and T. Warabisako 34 (1994) 141
Numerical approach for high-efficiency a-Si solar cells, T. Sawada, N. Terada, T. Takahama, H. Tarui, M. Tanaka, S. Tsuda and S. Nakano 34 (1994) 367
Measuring and modelling of a-Si,Ge:H solar cells, S. Wagner, K. Vasanth, M. Nakata, J. Yang and S. Guha 34 (1994) 373
Amorphous silicon solar cell computer model incorporating the effects of TCO/a-Si:C:H junction, F. Smole, M. Topič and J. Furlan 34 (1994) 385

Semiconductor doping

Deep defect determination by the constant photocurrent method (CPM) in annealed or light soaked amorphous hydrogenated silicon (a-Si:H), A. Mettler, N. Wyrsch, M. Goetz and A. Shah 34 (1994) 533

Semiconductor growth

Semiconductor liquid phase epitaxy for solar cell application, M. Konuma, I. Silier, E. Czech and E. Bauser 34 (1994) 251

Semiconductor junctions

Simplified high-efficiency silicon cell processing, P.A. Basore, J.M. Gee, M.E. Buck, W.K. Schubert and D.S. Ruby 34 (1994) 91

Semiconductor thin films

High efficiency silicon solar cells by plasma-CVD method, K. Fujimoto, Y. Sogawa, K. Shima, Y. Okayasu and K. Kumagai 34 (1994) 193

Silicon

The PV Era is coming — the way to GENESIS, Y. Kuwano 34 (1994) 27
Buried Contact Silicon Solar Cells, S.R. Wenham, C.B. Honsberg and M.A. Green 34 (1994) 101
685 mV Open-circuit voltage laser grooved silicon solar cell, C.B. Honsberg, F. Yun, A. Ebong, M. Taouk, S.R. Wenham and M.A. Green 34 (1994) 117
Measurement of surface recombination velocity of silicon wafers under sunlight condition by novel photoluminescence surface state spectroscopy, T. Saitoh, Y. Nishimoto and H. Hasegawa 34 (1994) 161
Characterization of surface recombination velocity at Si solar cell surface under high injection level, T. Uematsu, Y. Nagata, H. Ohtsuka, T. Warabisako, H. Nomura and T. Saitoh 34 (1994) 169

Silicon compounds

Progress in multijunction amorphous silicon alloy-based solar cells and modules, S. Guha, J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu 34 (1994) 329

Silicon nitride, SiN

Large-area high-efficiency single crystalline silicon solar cells, K. Fukui, Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe 34 (1994) 111
Very low surface recombination velocities on 2.5 Ω cm Si wafers, obtained with low-temperature PECVD of Si-oxide and Si-nitride, C. Leguijt, P. Lölgen, J.A. Eikelboom, P.H. Amesz, R.A. Steeman, W.C. Sinke, P.M. Sarro, L.A. Verhoef, P.-P. Michiels, Z.H. Chen and A. Rohatgi 34 (1994) 177

Solar cell arrays

PV development in Thailand, C. Jivacate et al. 34 (1994) 57
The use of photovoltaics in a northern climate, E. Usher, G. Jean and G. Howell 34 (1994) 73

Solar cells

Status of amorphous silicon solar cell technologies in Japan, H. Sakai 34 (1994) 9

The PV Era is coming — the way to GENESIS, Y. Kuwano 34 (1994) 27
SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States, J.L. Stone 34 (1994) 41
Recent progress in national photovoltaic project in Korea, J. Song 34 (1994) 51
Transfer of buried contact cell laboratory sequences into commercial production, M.A. Green, S.R. Wenham, C.B. Honsberg and D. Hogg 34 (1994) 83
Buried Contact Silicon Solar Cells, S.R. Wenham, C.B. Honsberg and M.A. Green 34 (1994) 101
Large-area high-efficiency single crystalline silicon solar cells, K. Fukui, Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe 34 (1994) 111
685 mV Open-circuit voltage laser grooved silicon solar cell, C.B. Honsberg, F. Yun, A. Ebong, M. Taouk, S.R. Wenham and M.A. Green 34 (1994) 117
Design and properties of a refractive static concentrator module, K. Yoshioka, K. Endoh, M. Kobayashi, A. Suzuki and T. Saitoh 34 (1994) 125
Model optimization of photovoltaic cells, B. Sørensen 34 (1994) 133
Cell structures with low–high heterojunction of c-Si and μc-Si:H under rear contact for improvement of efficiencies, M. Kaneiwa, S. Okamoto, I. Yamasaki, M. Nishida and T. Nammori 34 (1994) 183
Boosting the efficiency of solar cells fabricated on electromagnetic cold crucible cast multicrystalline silicon by means of hydrogen passivation, H.E. Elgamel, M.Y. Ghannam, C. Vinckier, J. Nijs, R. Mertens and R. Van Overstraeten 34 (1994) 237
Purification of metallurgical silicon up to solar grade, N. Yuge, H. Baba, Y. Sakaguchi, K. Nishikawa, H. Terashima and F. Aratani 34 (1994) 243
Fabrication of poly-crystalline silicon films using plasma spray method, F. Tamura, Y. Okayasu and K. Kumagai 34 (1994) 263
Fabrication technology for large-area a-Si solar cells, Y. Ichikawa 34 (1994) 321
Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates, G. Tao, M. Zeman and J.W. Metselaar 34 (1994) 359
Measuring and modelling of a-Si,Ge:H solar cells, S. Wagner, K. Vasanth, M. Nakata, J. Yang and S. Guha 34 (1994) 373
Amorphous silicon solar cell computer model incorporating the effects of TCO/a-Si:C:H junction, F. Smole, M. Topič and J. Furlan 34 (1994) 385
The wave nature of light in computer analysis of solar cells, P. Popović, J. Furlan and W. Kusian 34 (1994) 393
Amorphous silicon oxide and its application to metal/n-i-p/ITO type a-Si solar cells, P. Sichanugrist, T. Sasaki, A. Asano, Y. Ichikawa and H. Sakai 34 (1994) 415
Control of a-SiGe:H film quality with regard to its composition, K. Sayama, A. Terakawa, M. Shima, E. Maruyama, K. Ninomiya, H. Tarui, S. Tsuda and S. Nakano 34 (1994) 423
Light-induced recovery of a-Si solar cells, S. Fujikake, H. Ota, M. Ohsawa, T. Hama, Y. Ichikawa and H. Sakai 34 (1994) 449
Accelerated degradation test method for a-Si PV modules, S. Igari, J. Nose, T. Hiruma, F. Nagamine and K. Fujisawa 34 (1994) 473
Growth of high quality microcrystalline silicon by layer-by-layer deposition technique, K.C. Park, S.K. Kim, M. Park, J.M. Jun, K.H. Lee and J. Jang 34 (1994) 509

Solar radiation

Progress in multijunction amorphous silicon alloy-based solar cells and modules, S. Guha, J. Yang, A. Banerjee, T. Glatfelter, K. Hoffman and X. Xu 34 (1994) 329

Spectral response

Apparent "gettering" of the Staebler–Wronski effect in amorphous silicon solar cells, R.E.I. Schropp, M.B. von der Linden, J. Daey Ouwens and H. de Gooijer 34 (1994) 455

Structural properties

Characterization of hydrogenated amorphous silicon–carbon films deposited by hybrid-plasma CVD, T. Fujii, K. Sameshima, H. Okada, K. Yoshida, T. Hashimoto, M. Yoshimoto, T. Fuyuki and H. Matsunami 34 (1994) 409
Characterization of high quality a-Si:H for solar cells at low energy and at low temperature by PDS, S. Nonomura, T. Nishiwaki, E. Nishimura, S. Hasegawa, T. Itoh and S. Nitta 34 (1994) 549
Molecular dynamics simulation of amorphous silicon with Tersoff potential, T. Ohira, T. Inamuro and T. Adachi 34 (1994) 565

Textured surfaces

Large-area high-efficiency single crystalline silicon solar cells, K. Fukui, Y. Fukawa, H. Takahashi, K. Okada, M. Takayama, K. Shirasawa and H. Watanabe 34 (1994) 111
Semiconductor liquid phase epitaxy for solar cell application, M. Konuma, I. Silier, E. Czech and E. Bauser 34 (1994) 251
Optimization of ZnO for front and rear contacts in a-Si solar cells, W.W. Wenas, A. De, A. Yamada, M. Konagai and K. Takahashi 34 (1994) 313
Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates, G. Tao, M. Zeman and J.W. Metselaar 34 (1994) 359
Surface microstructures of ZnO coated SnO_2:F films, T. Ikeda, K. Sato, Y. Hayashi, Y. Wakayama, K. Adachi and H. Nishimura 34 (1994) 379

Thermal annealing

Molecular dynamics simulation of amorphous silicon with Tersoff potential, T. Ohira, T. Inamuro and T. Adachi 34 (1994) 565

Thin film solar cells

Status of amorphous silicon solar cell technologies in Japan, H. Sakai 34 (1994) 9
Solar cells based on $CuInSe_2$ and related compounds: recent progress in Europe, H.W. Schock 34 (1994) 19
SOLAR 2000: the next critical step towards large-scale commercialization of photovoltaics in the United States, J.L. Stone 34 (1994) 41
High-efficient operation of large-area (100 cm^2) thin film polycrystalline silicon solar cell based on SOI structure, S. Arimoto, H. Morikawa, M. Deguchi, Y. Kawama, Y. Matsuno, T. Ishihara, H. Kumabe and T. Murotani 34 (1994) 257
Sub-5 μm thin film c-Si solar cell and optical confinement by diffuse reflective-substrate, R. Shimokawa, K. Ishii, H. Nishikawa, T. Takahashi, Y. Hayashi, I. Saito, F. Nagamine and S. Igari 34 (1994) 277
Polycrystalline Si thin-film solar cell prepared by solid phase crystallization (SPC) method, T. Matsuyama, T. Baba, T. Takahama, S. Tsuda and S. Nakano 34 (1994) 285
Accurate generation rate profiles in a-Si:H solar cells with textured TCO substrates, G. Tao, M. Zeman and J.W. Metselaar 34 (1994) 359
Measuring and modelling of a-Si,Ge:H solar cells, S. Wagner, K. Vasanth, M. Nakata, J. Yang and S. Guha 34 (1994) 373
Microcrystalline silicon carbide — New useful material for improvement of solar cell performance, W. Ma, C.C. Lim, T. Saida, H. Okamoto and Y. Hamakawa 34 (1994) 401
Long-term reliability of amorphous silicon solar cells, K. Takahisa, K. Nakamura, S. Nakazawa, Y. Sugiyama, J. Nose, S. Igari and T. Hiruma 34 (1994) 485

Low temperature Si crystal growth by alternating deposition and hydrogen etching sequences and its application to the p-layer of a-Si:H solar cells, K. Yamamoto, T. Suzuki, K. Kondo, T. Okamoto, M. Yamaguchi, M. Izumina and Y. Tawada 34 (1994) 501

Tin oxide

Surface microstructures of ZnO coated SnO_2:F films, T. Ikeda, K. Sato, Y. Hayashi, Y. Wakayama, K. Adachi and H. Nishimura 34 (1994) 379

Transparent conductors

Surface microstructures of ZnO coated SnO_2:F films, T. Ikeda, K. Sato, Y. Hayashi, Y. Wakayama, K. Adachi and H. Nishimura 34 (1994) 379

Zinc oxide, ZnO

Optimization of ZnO for front and rear contacts in a-Si solar cells, W.W. Wenas, A. De, A. Yamada, M. Konagai and K. Takahashi 34 (1994) 313
Surface microstructures of ZnO coated SnO_2:F films, T. Ikeda, K. Sato, Y. Hayashi, Y. Wakayama, K. Adachi and H. Nishimura 34 (1994) 379